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1. Global joint venture starts operations as WeEn Semiconductors

Dear customer.

As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

In this document where the previous NXP references remain, please use the new links as shown below.

WWW - For www.nxp.com use www.ween-semi.com

Email - For salesaddresses@nxp.com use salesaddresses@ween-semi.com

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If you have any questions related to this document, please contact our nearest sales office via e-mail or phone (details via salesaddresses@ween-semi.com).

Thank you for your cooperation and understanding,

WeEn Semiconductors



DISCRETE SEMICONDUCTORS

DATA SHEET

BYV29 seriesRectifier diodes ultrafast

Product specification

September 1998



NXP Semiconductors Product specification

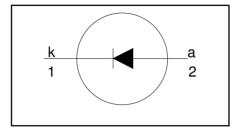
Rectifier diodes ultrafast

BYV29 series

FEATURES

- · Low forward volt drop
- · Fast switching
- · Soft recovery characteristic
- · High thermal cycling performance
- · Low thermal resistance

SYMBOL



QUICK REFERENCE DATA

 $V_R = 300 \text{ V} / 400 \text{ V} / 500 \text{ V}$ $V_F \le 1.03 \text{ V}$ $I_{F(AV)} = 9 \text{ A}$ $t_{rr} \le 60 \text{ ns}$

GENERAL DESCRIPTION

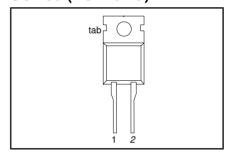
Ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYV29 series is supplied in the conventional leaded SOD59 (TO220AC) package.

PINNING

DESCRIPTION
cathode
anode
cathode

SOD59 (TO220AC)



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	. MAX.		UNIT	
V	Dools was atitized was assessed well-asses	BYV29		-300	-400	-500	
V _{RRM}	Peak repetitive reverse voltage Crest working reverse voltage		-	300 300	400 400	500 500	V
$V_{\rm RWM}$	Continuous reverse voltage		-	300	400	500	
I _{F(AV)}	Average forward current ¹	square wave; $\delta = 0.5$; $T_{mb} \le 123 ^{\circ}\text{C}$	-		9		Α
I _{FRM}	Repetitive peak forward current	$t = 25 \mu s; δ = 0.5;$ $T_{mb} \le 123 °C$	-		18		Α
I _{FSM}	Non-repetitive peak forward	t = 10 ms	-		100		Α
1 0.00	current.	t = 8.3 ms sinusoidal; with reapplied	-		110		Α
l_	_	$V_{RRM(max)}$					
$\begin{bmatrix} T_{stg} \\ T_{i} \end{bmatrix}$	Storage temperature Operating junction temperature		-40 -		150 150		.C

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance junction to mounting base		-	-	2.5	K/W
R _{th j-a}	Thermal resistance junction to ambient	in free air.	1	60	1	K/W

¹ Neglecting switching and reverse current losses.

NXP Semiconductors Product specification

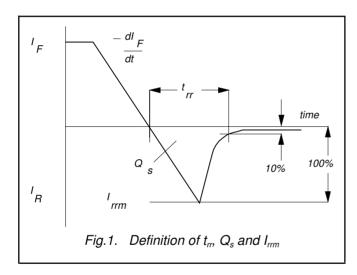
Rectifier diodes ultrafast

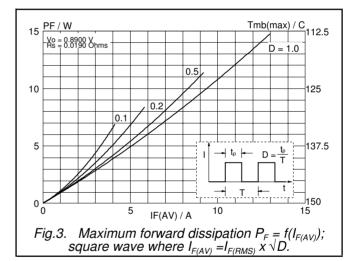
BYV29 series

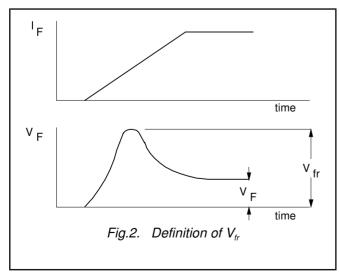
ELECTRICAL CHARACTERISTICS

T_i = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	Forward voltage	$I_{\rm F} = 8 \text{ A}; T_{\rm i} = 150^{\circ}\text{C}$	-	0.90	1.03	V
	_	$I_F = 8 \text{ A}$	-	1.05	1.25	V
		$I_{\rm F} = 20 \text{ A}$	-	1.20	1.40	V
l _R	Reverse current	$V_R = V_{RRM}$	-	2.0	50	μΑ
		$V_{R} = V_{RRM}^{(a)}; T_{j} = 100 ^{\circ}C$ $I_{F} = 2 ^{\circ}A ^{\circ}to ^{\circ}V_{R} \geq 30 ^{\circ}V;$	-	0.1	0.35	mΑ
Q_s	Reverse recovery charge	$I_{\rm F} = 2 {\rm A} {\rm to} {\rm V}_{\rm R}^{\prime} \ge 30 {\rm V};$	-	40	60	nC
		$dI_F/dt = 20 A/\mu s$				
t _{rr}	Reverse recovery time	$I_F = 1 \text{ A to } V_R \ge 30 \text{ V};$	-	50	60	ns
		$dI_F/dt = 100 \text{ A}/\mu \text{s}$				
l I _{rrm}	Peak reverse recovery current	$I_{\rm F} = 10 \text{ A to } V_{\rm R} \ge 30 \text{ V};$	-	4.0	5.5	Α
	1	$dI_{F}/dt = 50 \text{ A/}\mu\text{s}; T_{i} = 100^{\circ}\text{C}$				
V_{fr}	Forward recovery voltage	$I_F = 10 \text{ A}; dI_F/dt = 10 \text{ A}/\mu\text{s}$	-	2.5	-	V







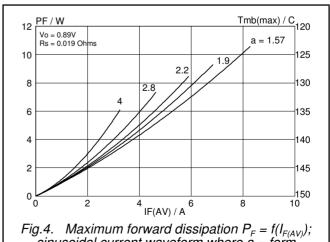
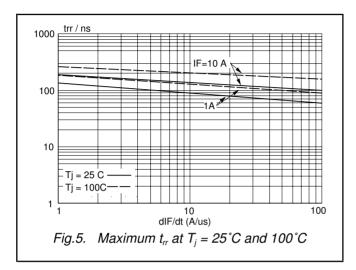


Fig.4. Maximum forward dissipation $P_F = f(I_{F(AV)})$; sinusoidal current waveform where a = form factor = $I_{F(RMS)} / I_{F(AV)}$.

NXP Semiconductors Product specification

Rectifier diodes ultrafast

BYV29 series



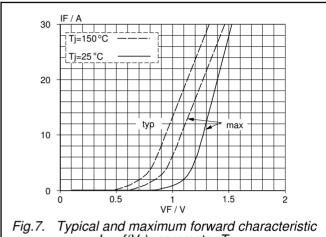
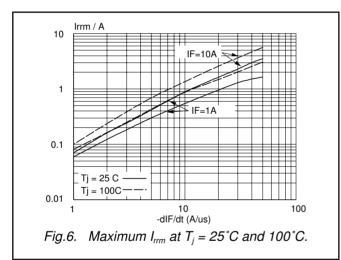
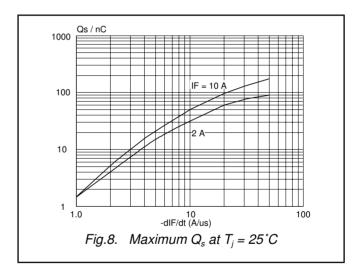
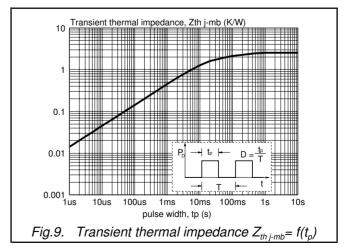


Fig.7. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_j





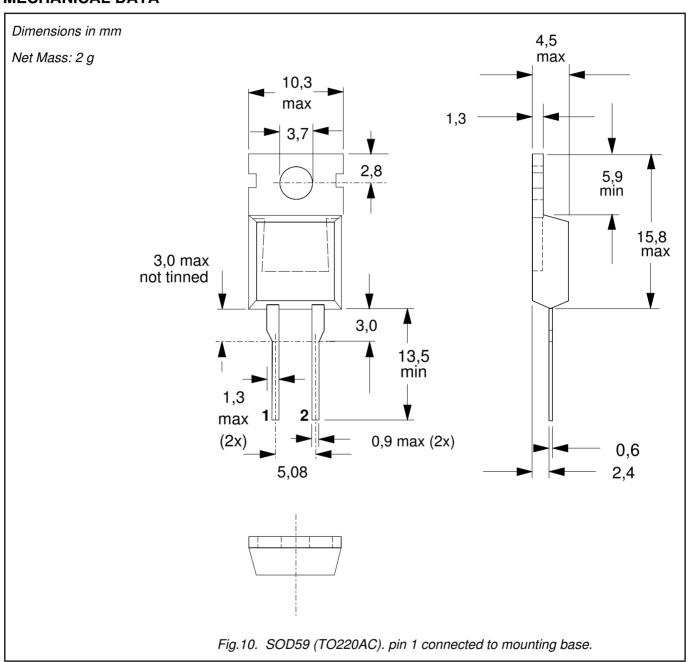


NXP Semiconductors Product specification

Rectifier diodes ultrafast

BYV29 series

MECHANICAL DATA



- Refer to mounting instructions for TO220 envelopes.
 Epoxy meets UL94 V0 at 1/8".

Legal information

DATA SHEET STATUS

DOCUMENT STATUS(1)	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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- 1. Please consult the most recently issued document before initiating or completing a design.
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Contact information

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